

As of 06/30/2026

Fund Description

Kurv Memory Select ETF seeks to provide targeted exposure to the companies dominating memory chip production.

Fund Details

Ticker	KMEM
CUSIP	500948781
ISIN	US5009487811
Primary Exchange	Cboe BZX
Expense Ratio	0.65%
Inception Date	06/30/2026

Fund Benefits



Pure-Play Memory Exposure

Access the companies at the core of memory chip production through a more focused and selective approach to memory exposure.



Built for the AI Era

Gain concentrated exposure to the critical layer powering AI infrastructure and next-generation computing workloads.



Supply/Demand Imbalance Opportunity

Own the bottleneck of AI as memory demand accelerates faster than supply.

Fund Performance

As of --/--/2026

Annualized

	1M	3M	6M	YTD	Since Inception	1YR	Since Inception
NAV	--%	--%	--%	--%	--%	--%	--%
MKT	--%	--%	--%	--%	--%	--%	--%

The performance data quoted represents past performance and does not guarantee future results. Investment return and principal value of an investment will fluctuate so that an investor's shares, when redeemed, may be worth more or less than their original cost. Current performance may be higher or lower than the performance quoted. High short-term performance may be unusual, and investors should not expect such performance to be repeated. Performance of less than one year is cumulative. For the most recent month-end performance, please call 1-833-955-KURV (5878) or visit [kurvinvest.com](#).

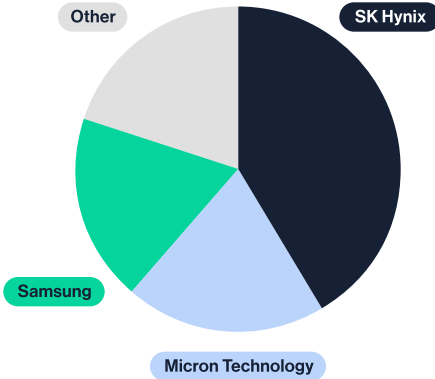
This material must be preceded or accompanied by a Prospectus. To view the fund prospectus please [click here](#). The Fund may not be suitable for all investors. There is no guarantee that the Fund's investment strategy will be properly implemented, and an investor may lose some or all of its investment. In addition, an investor may lose its investment even if the strategy is properly implemented.

Kurv ETFs are bought and sold at market price (not NAV) and are not individually redeemed from the Fund. Total Returns are calculated using the daily 4:00pm EST net asset value (NAV). Market price returns reflect the midpoint of the bid/ask spread as of the close of trading on the exchange where Fund shares are listed. Market price returns do not represent the returns you would receive if you traded shares at other times.

Fund Exposure with Look-Through

as of 6/30/2026, updated monthly

SK Hynix	41.53%
Micron Technology	19.85%
Samsung	18.81%
Other	19.76%



Important Information

Investing in the fund involves a high degree of risk. Principal loss is possible.

An investor should consider the investment objectives, risks, charges, and expenses of the Fund carefully before investing. To obtain a prospectus containing this and other information, please call 1-833955-KURV (5878). Read the prospectus carefully before investing.

Fund Objective: The Fund seeks to maximize total return.

An investment in the Fund entails risk, including the loss of principal. The Fund is not a complete investment program, and investors should review the risks associated with the Fund before investing. The Fund is an actively managed portfolio, and the portfolio managers will apply investment techniques and risk analyses that may not produce the desired result. There can be no guarantee that the Fund will meet its investment objective.

As an ETF, the Fund is exposed to the additional risks, including: (1) concentration risk associated with Authorized Participants, market makers, and liquidity providers. Such concentration could negatively impact liquidity; (2) costs and risks associated with frequent trading; (3) market prices may differ from the Fund's net asset value; and (4) liquidity risk due to a potential lack of trading volume.

Fund Risks: The Fund seeks to primarily invest under normal circumstances in companies, domestic or foreign, that design, manufacture, and distribute memory chips (memory chip activities) ("Memory Companies"). Memory chips are semiconductor devices designed for the temporary or permanent storage and retrieval of data in computer systems. Memory chips include, but are not limited to: Dynamic Random Access Memory (DRAM): Volatile memory chips that require periodic electrical refreshing to retain data, commonly used as main memory in computers, servers, smartphones, and other computing devices; Static Random Access Memory (SRAM): Volatile memory chips that retain data without refreshing as long as power is supplied, typically used for cache memory in processors; Random Access Memory (RAM): A general category of memory allowing data to be read from or written to in any order, encompassing both DRAM and SRAM technologies; Flash Memory: Non-volatile memory chips that retain data without power, including NAND flash (used in solid-state drives, USB drives, and memory cards) and NOR flash (used in embedded systems for code storage); Emerging memory types (e.g. MRAM, ReRAM).

Memory Companies Risk: The Fund invests in Memory Companies, which may have limited product lines, markets, financial resources or personnel and are subject to the risks of changes in business cycles, world economic growth, technological progress and government regulation. These companies are also heavily dependent on intellectual property rights, and challenges to or misappropriation of such rights could have a material adverse effect on such companies. Securities of Memory Companies tend to be more volatile than securities of companies that rely less heavily on technology. Memory Companies typically engage in significant amounts of spending on research and development, and rapid changes to the field could have a material adverse effect on a company's operating results. Additionally, the development, manufacturing, and commercialization of semiconductor memory technologies, including HBM, DRAM and NAND, as well as related subsystems, equipment, materials, and services, are complex and evolving, and may face unforeseen technical challenges (including yield and integration issues), supply chain disruptions, intense competition and pricing volatility, regulatory developments (including export controls), and market acceptance uncertainties. As a result, investments in Memory Companies may be subject to higher levels of risk and volatility.

Active Management Risk: The Fund is actively managed, which means that investment decisions are made based on investment views. There is no guarantee that the investment views will produce the desired results or expected returns, which may cause the Fund to fail to meet its investment objective or to underperform its benchmark index or funds with similar investment objectives and strategies.

Derivatives and Options Risk: The Fund's use of derivatives, including options, may pose risks in addition to those associated with directly investing in securities. These risks include market risk, imperfect correlation with the underlying issuer, volatility risk, liquidity risk, valuation risk, and legal or regulatory constraints. The value of options may be highly sensitive to changes in volatility, time decay, interest rates, and market events.

Distributor for Kurv ETFs: Foreside Fund Services, LLC